

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







Configurable Dual Supply Octal Transceiver

with 3-State Outputs for 3 V Systems

The 74LVXC3245 is a 24-pin dual-supply, octal configurable voltage interface transceiver especially well suited for PCMCIA and other real time configurable I/O applications. The V_{CCA} pin accepts a 3.0 V supply level; the A port is a dedicated 3.0 V port. The V_{CCB} pin accepts a 3.0 V-to-5.0 V supply level. The B port is configured to track the V_{CCB} supply level. A 5.0 V level on the V_{CCB} pin will configure the I/O pins at a 5.0~V level and a $3.0~V~V_{CCB}$ will configure the I/O pins at a 3.0 V level. The A port interfaces with a 3.0 V host system and the B port to the card slots. This device will allow the V_{CCB} voltage source pin and I/O pins on the B port to float when \overline{OE} is High. This feature is necessary to buffer data to and from a PCMCIA socket that permits PCMCIA cards to be inserted and removed during normal operation. The Transmit/Receive (T/\overline{R}) input determines the direction of data flow. Transmit (active-High) enables data from the A port to B port. Receive (active-Low) enables data from the B port to the A port.

Features

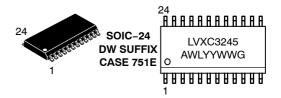
- Bidirectional Interface Between 3.0 V and 3.0 V/5.0 V Buses
- Control Inputs Compatible with TTL Level
- Outputs Source/Sink Up to 24 mA
- Guaranteed Simultaneous Switching Noise Level and Dynamic Threshold Performance
- Available in SOIC and TSSOP Packages
- Flexible V_{CCB} Operating Range
- Allows B Port and V_{CCB} to Float Simultaneously When \overline{OE} is High
- Functionally Compatible With the 74 Series 245
- Pb-Free Packages are Available*

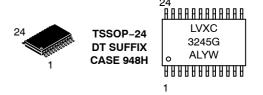


ON Semiconductor®

http://onsemi.com

MARKING DIAGRAMS





A = Assembly Location

WL, L = Wafer Lot YY, Y = Year WW, W = Work Week G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

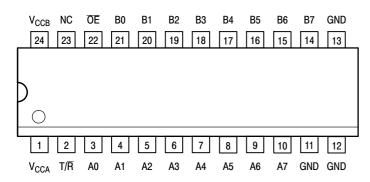


Figure 1. 24-Lead Pinout (Top View)

PIN NAMES

Pins	Function
OE	Output Enable Input
T/R	Transmit/Receive Input
A0-A7	Side A 3-State Inputs or 3-State Outputs
B0-B7	Side B 3-State Inputs or 3-State Outputs

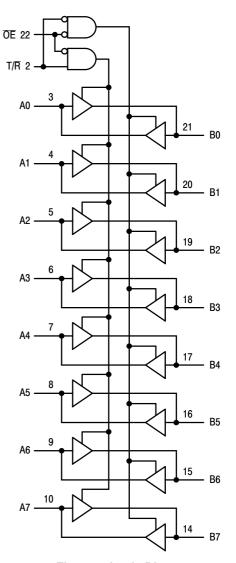


Figure 2. Logic Diagram

INP	UTS	OPERATING MODE
ŌĒ	T/R	Non-Inverting
L	L	B Data to A Bus
L	Н	A Data to B Bus
Н	Х	Z

H = High Voltage Level; L = Low Voltage Level; Z = High Impedance State; X = High or Low Voltage Level and Transitions are Acceptable; for I_{CC} reasons, Do Not Float Inputs

MAXIMUM RATINGS

Symbol	Parameter		Value	Condition	Unit
V _{CCA} , V _{CCB}	DC Supply Voltage		-0.5 to +7.0		V
VI	DC Input Voltage	ŌE, T∕R	-0.5 to V _{CCA} +0.5		V
V _{I/O}	DC Input/Output Voltage	An	-0.5 to V_{CCA} +0.5		V
		Bn	-0.5 to V_{CCB} +0.5		V
I _{IK}	DC Input Diode Current	ŌE, T∕R	±20	V _I < GND	mA
I _{OK}	DC Output Diode Current		±50	$V_O < GND; V_O > V_{CC}$	mA
Io	DC Output Source/Sink Current		±50		mA
I _{CC} , I _{GND}	DC Supply Current	Per Output Pin Maximum Current	±50 ±200		mA
T _{STG}	Storage Temperature Range		-65 to +150		°C
	DC Latchup Source/Sink Current		±300		mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

Symbol	Para	Parameter			
V _{CCA} , V _{CCB}	Supply Voltage (V _{CCA} ≤ V _{CCB})	V _{CCA} V _{CCB}	2.3 3.0	3.6 5.5	V
VI	Input Voltage	ŌĒ, T/R	0	V _{CCA}	V
V _{I/O}	Input/Output Voltage	An Bn	0	V _{CCA} V _{CCB}	V
T _A	Operating Free-Air Temperature	-40	+85	°C	
Δt/ΔV	Minimum Input Edge Rate V _{IN} from 30% to 70% of V _{CC} ; V _{CC} at 3.0 V, 4	5.5 V, 5.5 V	0	8	ns/V

DC ELECTRICAL CHARACTERISTICS

						T _A =	25°C	T _A = −40 to +85°C	
Symbol	Parameter		Condition	V _{CCA}	V _{CCB}	Тур	Gı	uaranteed Limits	Unit
V _{IHA}	Minimum HIGH Level Input Voltage	An OE T/R	V _{OUT} ≤ 0.1 V	2.3 3.0 3.6	3.0 3.6 5.5		2.0 2.0 2.0	2.0 2.0 2.0	V
V _{IHB}		Bn	or ≥ V _{CC} – 0.1 V	2.3 3.0 3.6	3.0 3.6 5.5		2.00 2.00 3.85	2.00 2.00 3.85	V
V _{ILA}	Maximum LOW Level Input Voltage	An OE T/R	V _{OUT} ≤ 0.1 V	2.3 3.0 3.6	3.0 3.6 5.5		0.8 0.8 0.8	0.8 0.8 0.8	V
V _{ILB}		Bn	or ≥ V _{CC} – 0.1 V	2.3 3.0 3.6	3.0 3.6 5.5		0.80 0.80 1.65	0.80 0.80 1.65	V
V _{OHA}	Minimum HIGH Level Output Voltage		$I_{OUT} = -100 \mu A$ $I_{OH} = -12 mA$ $I_{OH} = -24 mA$ $I_{OH} = -12 mA$ $I_{OH} = -24 mA$	3.0 3.0 3.0 2.3 2.3	3.0 3.0 3.0 3.0 4.5	2.99 2.85 2.65 2.50 2.30	2.90 2.56 2.35 2.30 2.10	2.90 2.46 2.25 2.20 2.00	V
V _{OHB}			$I_{OUT} = -100 \mu A$ $I_{OH} = -12 \text{ mA}$ $I_{OH} = -24 \text{ mA}$ $I_{OH} = -24 \text{ mA}$	3.0 3.0 3.0 3.0	3.0 3.0 3.0 4.5	2.99 2.85 2.65 4.25	2.90 2.56 2.35 3.86	2.90 2.46 2.25 3.76	V

DC ELECTRICAL CHARACTERISTICS

						T _A =	25°C	T _A = -40 to +85°C	
Symbol	Parameter		Condition	V _{CCA}	V _{CCB}	Тур	Gı	uaranteed Limits	Unit
V _{OLA}	Maximum LOW Level Output Voltage		$\begin{split} I_{OUT} &= 100 \ \mu\text{A} \\ I_{OL} &= 24 \ \text{mA} \\ I_{OL} &= 12 \ \text{mA} \\ I_{OL} &= 24 \ \text{mA} \end{split}$	3.0 3.0 2.7 2.7	3.0 3.0 3.0 4.5	0.002 0.21 0.11 0.22	0.10 0.36 0.36 0.42	0.10 0.44 0.44 0.50	V
V _{OLB}			I _{OUT} = 100 μA I _{OL} = 24 mA I _{OL} = 24 mA	3.0 3.0 3.0	3.0 3.0 4.5	0.002 0.21 0.18	0.10 0.36 0.36	0.10 0.44 0.44	٧
I _{IN}	Max Input Leakage Current	OE, T/R	V _I = V _{CCA} , GND	3.6 3.6	3.6 5.5		±0.1 ±0.1	±1.0 ±1.0	μΑ
I _{OZA}	Max 3-State Output Leakage	An	$\begin{aligned} & V_{I} = V_{IH}, V_{IL} \\ & \overline{OE} = V_{CCA} \\ & V_{O} = V_{CCA}, GND \end{aligned}$	3.6 3.6	3.6 5.5		±0.5 ±0.5	±5.0 ±5.0	μА
l _{OZB}	Max 3-State Output Leakage	Bn	$\begin{aligned} & V_{I} = V_{IH}, V_{IL} \\ & \overline{OE} = V_{CCA} \\ & V_{O} = V_{CCB}, GND \end{aligned}$	3.6 3.6	3.6 5.5		±0.5 ±0.5	±5.0 ±5.0	μА
ΔI_{CC}	Maximum I _{CC} /Input	Bn	$V_I = V_{CCB} - 2.1 \text{ V}$	3.6	5.5	1.0	1.35	1.5	mA
		All In- puts	V _I = V _{CC} -0.6 V	3.6	3.6		0.35	0.5	mA
I _{CCA1}	Quiescent V _{CCA} Supply Current as B Port Floats		$\begin{aligned} &\text{An} = \text{V}_{\text{CCA}} \text{ or GND} \\ &\text{Bn} = \text{Open,} \\ &\overline{\text{OE}} = \text{V}_{\text{CCA}}, \\ &\overline{\text{T/R}} = \text{V}_{\text{CCA}}, \\ &\text{V}_{\text{CCB}} = \text{Open} \end{aligned}$	3.6	Open		5	50	μΑ
I _{CCA2}	Quiescent V _{CCA} Supply Current		$\begin{aligned} &An = V_{CCA} \text{ or GND} \\ &Bn = V_{CCB} \text{ or} \\ &GND, \ \overline{OE} = GND, \\ &T/\overline{R} = GND \end{aligned}$	3.6 3.6	3.6 5.5		5 5	50 50	μΑ
I _{CCB}	Quiescent V _{CCB} Supply Current		$\begin{aligned} &An = V_{CCA} \text{ or GND} \\ &Bn = V_{CCB} \text{ or} \\ &GND, \ \overline{OE} = GND, \\ &T/\overline{R} = V_{CCA} \end{aligned}$	3.6 3.6	3.6 5.5		5 8	50 80	μΑ
V _{OLPA}	Quiet Output Max Dy- namic V _{OL}		Notes 1, 2	3.3 3.3	3.3 5.0		0.8 0.8		V
V_{OLPB}			Notes 1, 2	3.3 3.3	3.3 5.0		0.8 1.5		٧
V_{OLVA}	Quiet Output Min Dy- namic V _{OL}		Notes 1, 2	3.3 3.3	3.3 5.0		-0.8 -0.8		٧
V_{OLVB}			Notes 1, 2	3.3 3.3	3.3 5.0		-0.8 -1.2		V
V_{IHDA}	Min HIGH Level Dy- namic Input Voltage		Notes 1, 3	3.3 3.3	3.3 5.0		2.0 2.0		V
V_{IHDB}			Notes 1, 3	3.3 3.3	3.3 5.0		2.0 3.5		٧
V_{ILDA}	Max LOW Level Dy- namic Input Voltage		Notes 1, 3	3.3 3.3	3.3 5.0		0.8 0.8		٧
V_{ILDB}			Notes 1, 3	3.3 3.3	3.3 5.0		0.8 1.5		V

Worst case package.
 Max number of outputs defined as (n). Data inputs are driven 0 V to V_{CC} level; one output at GND.
 Max number of data inputs (n) switching. (n-1) inputs switching 0 V to V_{CC} level. Input under test switching: V_{CC} level to threshold (V_{ILD}), 0 V to threshold (V_{ILD}), f = 1 MHz.

AC ELECTRICAL CHARACTERISTICS

			T _A :	= -40 to +85	5°C; C _L = 50) pF		
			_{CCA} = 2.7-3.0 _{CCB} = 4.5-5.		V _C			
Symbol	Parameter	Min	Typ (Note 4)	Max	Min	Typ (Note 5)	Max	Unit
t _{PHL} t _{PLH}	Propagation Delay A to B	1.0 1.0	4.8 3.9	8.5 7.0	1.0 1.0	5.5 5.2	9.0 8.5	ns
t _{PHL}	Propagation Delay B to A	1.0 1.0	3.8 4.3	7.0 8.0	1.0 1.0	4.4 5.1	7.5 8.0	ns
t _{PZL} t _{PZH}	Output Enable Time OE to B	1.0 1.0	4.7 4.8	8.5 9.0	1.0 1.0	6.0 6.1	9.5 10.0	ns
t _{PZL} t _{PZH}	Output Enable Time \overline{OE} to A	1.0 1.0	5.9 5.4	10.0 9.5	1.0 1.0	6.4 5.8	10.5 9.5	ns
t _{PHZ}	Output Disable Time OE to B	1.0 1.0	4.0 3.8	8.5 8.0	1.0 1.0	6.3 4.5	10.0 8.5	ns
t _{PHZ}	Output Disable Time OE to A	1.0 1.0	4.6 3.1	10.0 7.0	1.0 1.0	5.2 3.4	10.0 7.0	ns
t _{OSHL} t _{OSLH}	Output to Output Skew, Data to Output (Note 6)		1.0	1.5		1.0	1.5	ns

CAPACITIVE CHARACTERISTICS

Symbol	Parameter		Parameter Condition		Unit
C _{IN}	Input Capacitance		V _{CCA} = 3.3 V; V _{CCB} = 5.0 V	4.5	pF
C _{I/O}	Input/Output Capacitance		V _{CCA} = 3.3 V; V _{CCB} = 5.0 V	10	pF
C _{PD}	Power Dissipation Capacitance (Measured at 10 MHz)	A→B B→A	V _{CCB} = 5.0 V V _{CCA} = 3.3 V	50 40	pF

ORDERING INFORMATION

Device	Package	Shipping [†]
MC74LVXC3245DWR2	SOIC-24	1000 Tape & Reel
MC74LVXC3245DWR2G	SOIC-24 (Pb-Free)	1000 Tape & Reel
MC74LVXC3245DT	TSSOP-24*	62 Units / Rail
MC74LVXC3245DTG	TSSOP-24* (Pb-Free)	62 Units / Rail
MC74LVXC3245DTR2	TSSOP-24*	2500 Tape & Reel
MC74LVXC3245DTR2G	TSSOP-24* (Pb-Free)	2500 Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Typical values at V_{CCA} = 3.3 V, V_{CCB} = 5.0 V at 25°C.
 Typical values at V_{CCA} = 3.3 V, V_{CCB} = 3.3 V at 25°C.
 Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}); parameter guaranteed by design.

^{*}This package is inherently Pb-Free.

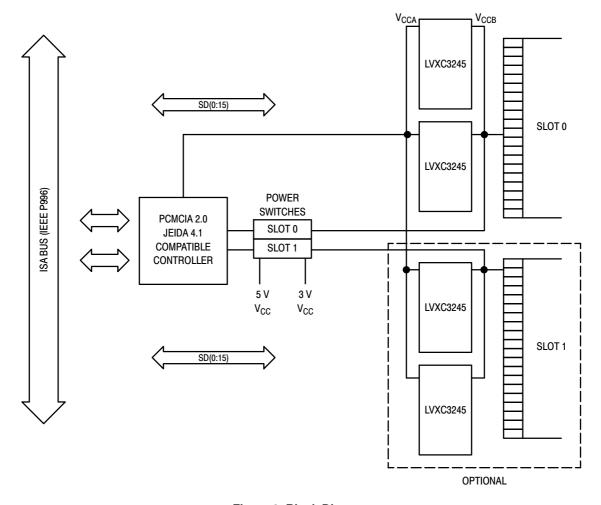


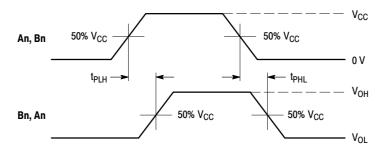
Figure 3. Block Diagram

Configurable I/O Application for PCMCIA Cards

The 74LVXC3245 is a dual–supply device well suited for PCMCIA configurable I/O applications. The LVXC3245 consumes less than 1mW of quiescent power in all modes of operation, making it ideal for low power notebook designs. The LVXC3245 meets all PCMCIA I/O voltage requirements at 5.0 V and 3.3 V operation. By tying the $V_{\rm CCB}$ pin to the card voltage supply, the PCMCIA card will always have

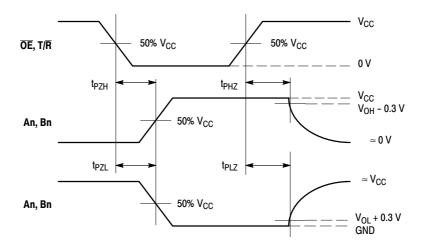
rail-to-rail output swings, maximizing the reliability of the interface

The V_{CCA} pin must always be tied to a 3.3 V power supply. This voltage connection provides internal references needed to account for variations in V_{CCB} . When connected as in the figure above, the LVXC3245 meets all the voltage and current requirements of the ISA bus standard (IEEE P996).



WAVEFORM 1 - PROPAGATION DELAYS

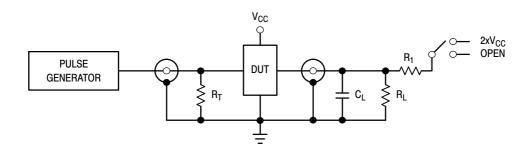
 t_R = t_F = 2.5 ns, 10% to 90%; f = 1 MHz; t_W = 500 ns



WAVEFORM 2 - OUTPUT ENABLE AND DISABLE TIMES

 t_R = t_F = 2.5 ns, 10% to 90%; f = 1 MHz; t_W = 500 ns

Figure 4. AC Waveforms



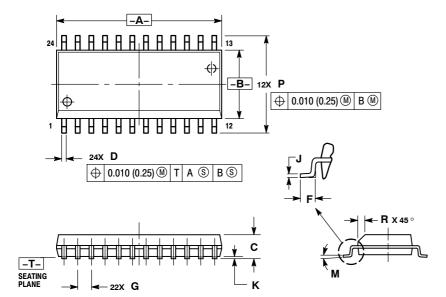
TEST	SWITCH
t _{PLH} , t _{PHL} , t _{PZH} , t _{PHZ}	Open
t _{PZL} , t _{PLZ}	2xV _{CC}

 C_L = 50 pF or equivalent (Includes jig and probe capacitance) R_L = R_1 = 500 Ω or equivalent R_T = Z_{OUT} of pulse generator (typically 50 Ω)

Figure 5. Test Circuit

PACKAGE DIMENSIONS

SOIC-24 **DW SUFFIX** CASE 751E-04 **ISSUE E**

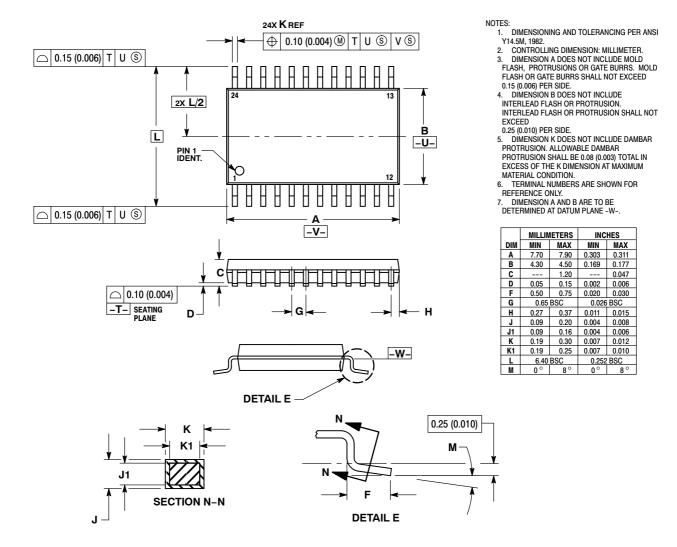


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE
- 4. MAXIMUM MUDL PRUTHUSION 0.15 (0.006) PER SIDE.
 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	15.25	15.54	0.601	0.612
В	7.40	7.60	0.292	0.299
С	2.35	2.65	0.093	0.104
D	0.35	0.49	0.014	0.019
F	0.41	0.90	0.016	0.035
G	1.27	BSC	0.050	BSC
J	0.23	0.32	0.009	0.013
K	0.13	0.29	0.005	0.011
M	0 °	8°	0°	8°
Р	10.05	10.55	0.395	0.415
R	0.25	0.75	0.010	0.029

PACKAGE DIMENSIONS

TSSOP-24 DT SUFFIX CASE 948H-01 ISSUF A



ON Semiconductor and are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlitt@onsemi.com N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910

Japan Customer Focus Center
Phone: 81–3–5773–3850

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative